

1 Characteristics

Table 2: Absolute ratings (limiting values), limiting values

Symbol	Parameter		Value	Unit	
I _{T(RMS)}	RMS on-state current (180 ° conduction angle)		T _C = 55 °C	0.8	A
I _{T(AV)}	Average on-state current (180 ° conduction angle)			0.5	
I _{TSM}	Non repetitive surge peak on-state current	t _p = 8.3 ms	T _j = 25 °C	8	A
		t _p = 10 ms		7	
I ² t	I ² t value for fusing				
di/dt	Critical rate of rise of on-state current I _G = 2 x I _{GT} , tr ≤ 100 ns	f = 60 Hz	T _j = 125 °C	30	A/μs
I _{GM}	Peak forward gate current	t _p = 20 μs	T _j = 125 °C	1	A
V _{DRM}	Repetitive peak off-state voltage		Max.	400	V
P _{G(AV)}	Average gate power dissipation		T _j = 125 °C	0.1	W
T _{stg}	Storage junction temperature range			-40 to +150	°C
T _j	Operating junction temperature range			-40 to +125	

Table 3: Electrical characteristics ($T_j = 25\text{ °C}$ unless otherwise specified)

Symbol	Test conditions			Value	Unit
I _{GT}	V _D = 12 V, R _L = 140 Ω		Max.	200	μA
V _{GT}			Max.	0.8	V
V _{GD}	V _D = V _{DRM} , R _L = 3.3 kΩ, R _{GK} = 1 kΩ	T _j = 125 °C	Min.	0.1	V
V _{RG}	I _{RG} = 10 μA		Min.	8	V
I _H	I _T = 50 mA, R _{GK} = 1 kΩ		Max.	5	mA
I _L	I _G = 1 mA, R _{GK} = 1 kΩ	T _j = 125 °C	Max.	6	mA
dV/dt ⁽¹⁾	V _D = 67 % V _{DRM} , R _{GK} = 1 kΩ	T _j = 125 °C	Min.	75	V/μs
V _{TM}	I _{TM} = 1.6 A, t _p = 380 μs	T _j = 25 °C	Max.	1.95	V
V _{to}	Threshold voltage	T _j = 125 °C	Max.	1.0	V
R _d	Dynamic resistance	T _j = 125 °C	Max.	600	mΩ
I _{DRM}	V _{DRM} R _{GK} = 1 kΩ	T _j = 25 °C	Max.	1	μA
		T _j = 125 °C	Max.	100	

Notes:
⁽¹⁾for both polarities of A2 referenced to A1.

Table 4: Thermal parameters

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient (DC)	150	°C/W
$R_{th(j-l)}$	Junction to lead (DC)	80	

1.1 Characteristics (curves)

Figure 1: Maximum average power dissipation versus average on-state current

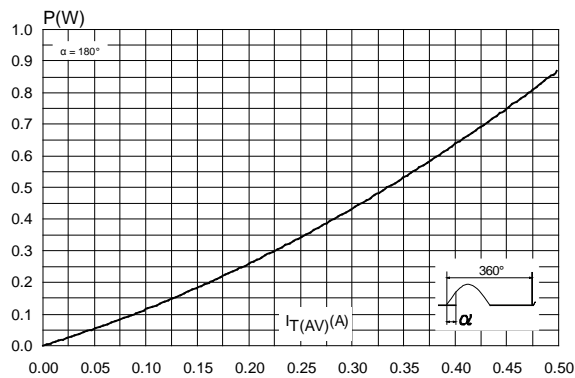


Figure 2: Average and D.C. on-state current versus lead temperature

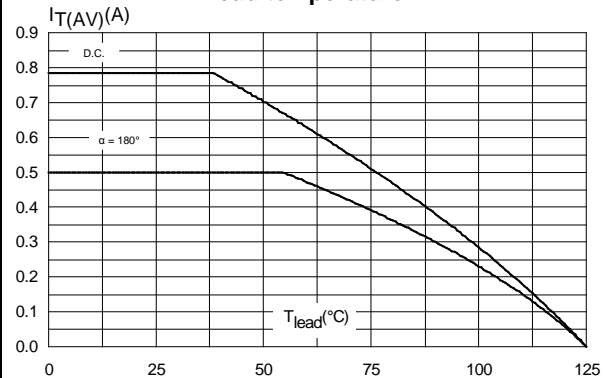


Figure 3: Average and D.C. on-state current versus ambient temperature (device mounted on FR4 with recommended pad layout)

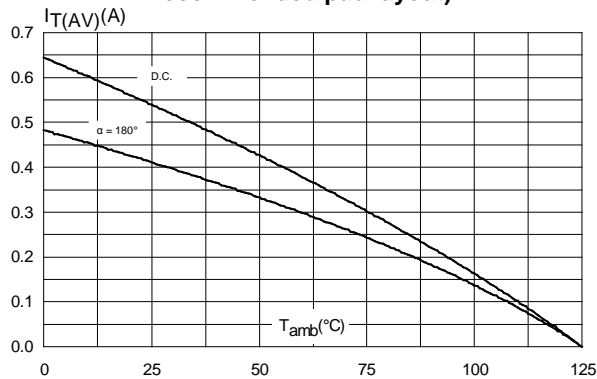


Figure 4: Relative variation of thermal impedance junction to ambient versus pulse duration

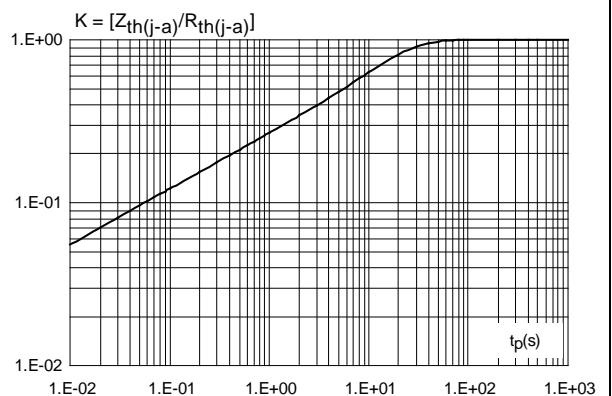


Figure 5: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

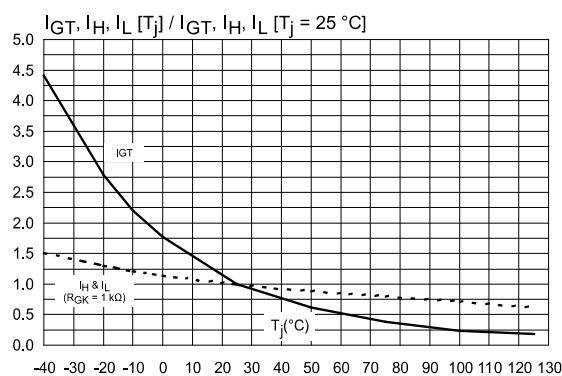


Figure 6: Relative variation of holding current versus gate-cathode resistance (typical values)

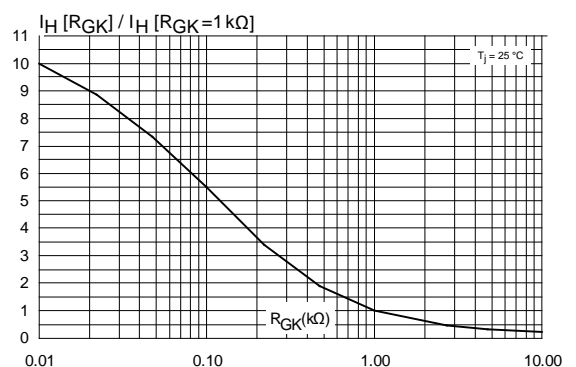


Figure 7: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values)

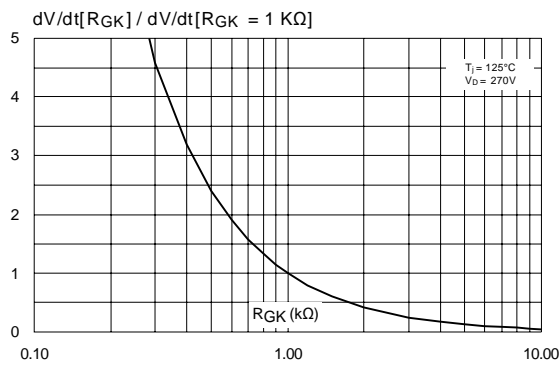


Figure 8: Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values)

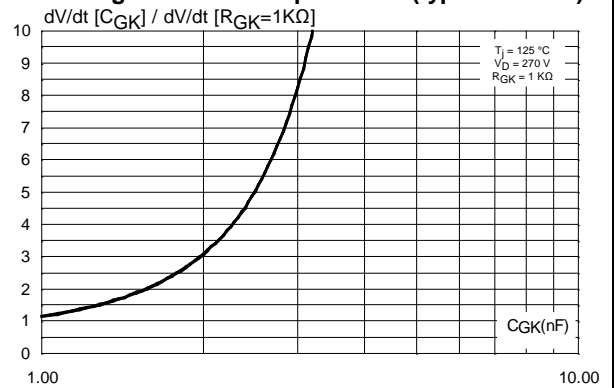


Figure 9: Surge peak on-state current versus number of cycles

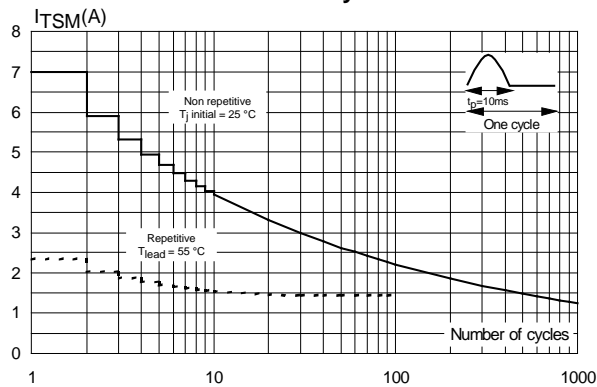


Figure 10: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

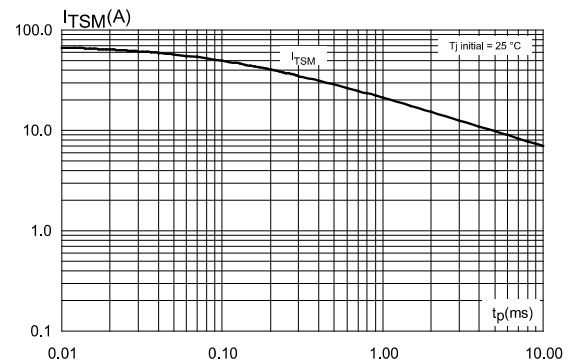
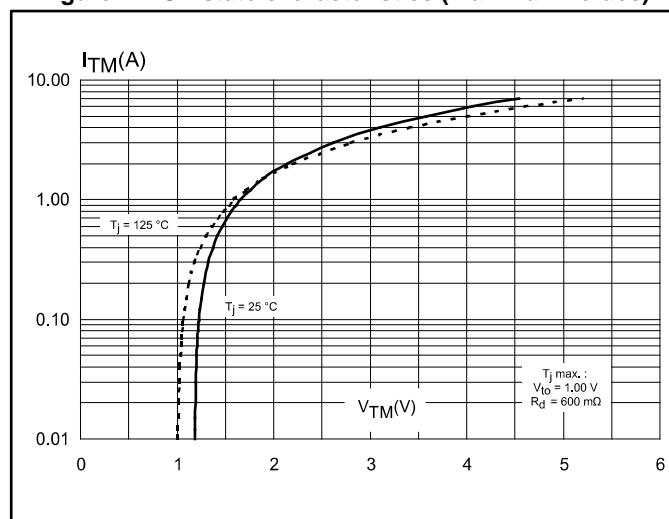


Figure 11: On-state characteristics (maximum values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TO-92 package information (for bag version)

Figure 12: TO-92 package outline (for bag version)

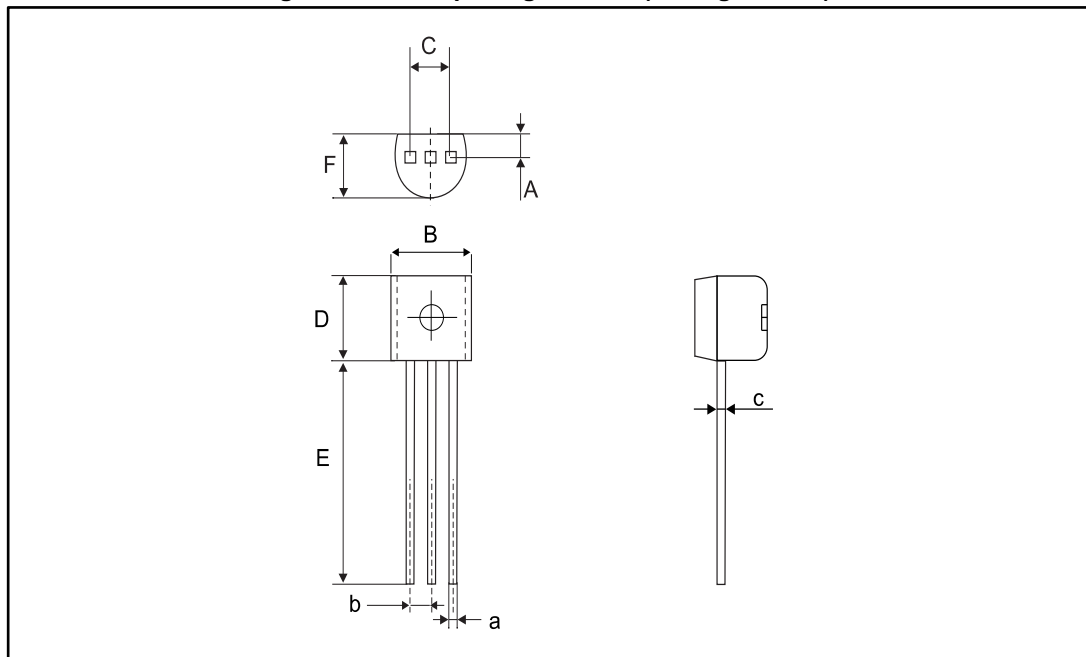


Table 5: TO-92 package mechanical data (for bag version)

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		1.35			0.0531	
B			4.70			0.1850
C		2.54			0.1000	
D	4.40			0.1732		
E	12.70			0.5000		
F			3.70			0.1457
a			0.50			0.0197
b		1.27			0.0500	
c			0.48			0.0189

Notes:

⁽¹⁾Inches given for reference only

2.2 TO-92 package information (for ammopack and tape and reel versions)

Figure 13: TO-92 package outline (for ammopack and tape and reel versions)

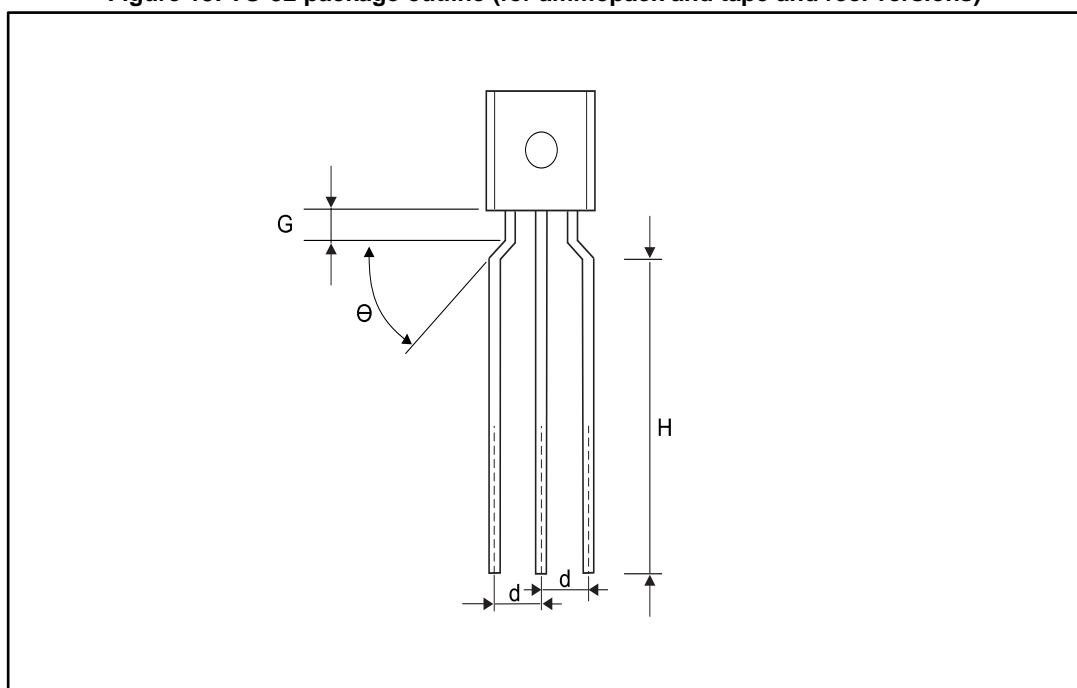


Table 6: TO-92 package mechanical data (for ammopack and tape and reel versions)

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
G	1.30	1.70	2.00	0.0511	0.0669	0.0787
H	7.69		9.69	0.3028		0.3815
d	2.40		2.90	0.0945		0.1142
θ	30°	40°	50°	30°	40°	50°

Notes:

⁽¹⁾Inches given for reference only

3 Ordering information

Figure 14: Ordering information scheme

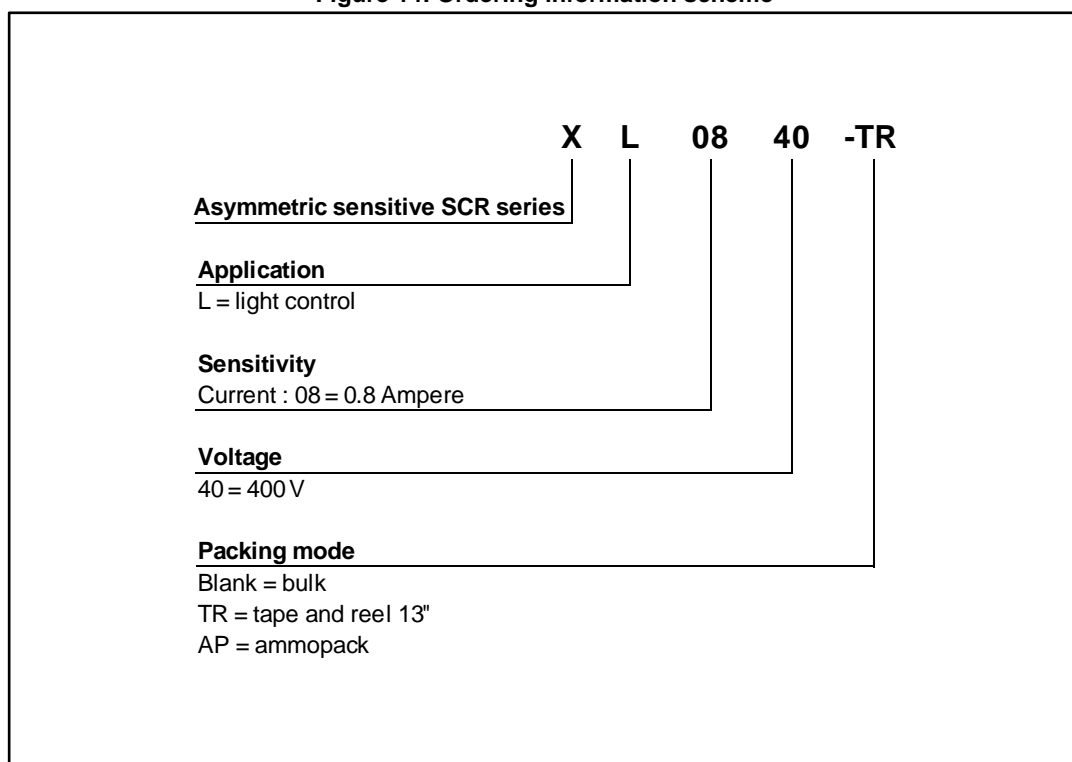


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
XL0840	XL0840	TO-92	0.2 g	2500	Bag
XL0840-AP	XL0840			2000	Ammopack not in dry bag
XL0840-TR	XL0840			2000	Tape and Reel 13 inches

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
Jan-2002	1	Initial release
07-Sep-2017	2	Updated package information section.

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